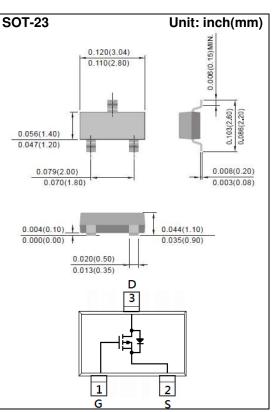
ΡΛΝ	ĴΪΤ
	SEMI CONDUCTOR

### **30V P-Channel Enhancement Mode MOSFET** -30 V Voltage Current -3.1A Features • RDS(ON), VGS@-10V, ID@-3.1A<98mΩ RDS(ON), VGS@-4.5V, ID@-2.2A<114mΩ RDS(ON), VGS@-2.5V, ID@-1.1A<165mΩ • • Advanced Trench Process Technology Specially Designed for Switch Load, PWM Application, etc. • Lead free in compliance with EU RoHS 2011/65/EU directive. • Green molding compound as per IEC61249 Std. (Halogen Free) **Mechanical Data** • Case: SOT-23 Package

- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0003 ounces, 0.0084 grams
- Marking: A03



### **Maximum Ratings and Thermal Characteristics** (T<sub>A</sub>=25<sup>°</sup>C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V <sub>DS</sub>	-30	V
Gate-Source Voltage		V <sub>GS</sub>	<u>+</u> 12	V
Continuous Drain Current		I <sub>D</sub>	-3.1	А
Pulsed Drain Current		I <sub>DM</sub>	-12.4	А
Power Dissipation	T <sub>a</sub> =25°C	P <sub>D</sub>	1.25	W
	Derate above 25°C		10	mW/°C
Operating Junction and Storage Tem	perating Junction and Storage Temperature Range		-55~150	°C
Typical Thermal resistance - Junction to Ambient <sup>(Note 3)</sup>		$R_{ extsf{ heta}JA}$	100	°C/W



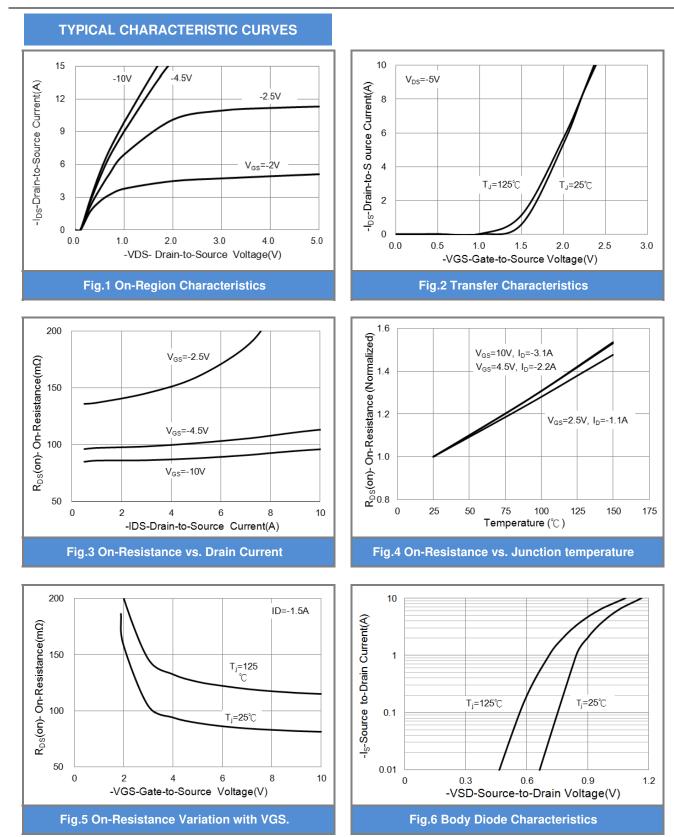
## **Electrical Characteristics** ( $T_A=25^{\circ}C$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static	STINDUL	TEST CONDITION	IVIIIN.	116.		01113
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =-250uA	-30	-	_	V
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , $I_{D}=-250$ uA	-0.5	-0.96	-1.3	V
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =-10V, I <sub>D</sub> =-3.1A	-	82	98	mΩ
		V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-2.2A	-	91	114	
		V <sub>GS</sub> =-2.5V, I <sub>D</sub> =-1.1A	-	115	165	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-30V, V <sub>GS</sub> =0V	-	-0.01	-1	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = <u>+</u> 12V, V <sub>DS</sub> =0V	-	<u>+</u> 10	<u>+</u> 100	nA
Dynamic						
Total Gate Charge	Qg	V <sub>DS</sub> =-15V, I <sub>D</sub> =-3.1A, V <sub>GS</sub> =-10V <sup>(Note 1,2)</sup>	-	11	-	nC
Gate-Source Charge	$Q_gs$		-	0.85	-	
Gate-Drain Charge	$Q_gd$		-	1.4	-	
Input Capacitance	Ciss	V <sub>DS</sub> =-15V, V <sub>GS</sub> =0V,	-	443	-	pF
Output Capacitance	Coss		-	38	-	
Reverse Transfer Capacitance	Crss	f=1.0MHZ	-	25	-	
Switching						
Turn-On Delay Time	td <sub>(on)</sub>		-	2.5	-	
Turn-On Rise Time	tr	V <sub>DD</sub> =-15V, I <sub>D</sub> =-3.1A, V <sub>GS</sub> =-10V,	-	32	-	ns
Turn-Off Delay Time	$td_{(off)}$		-	161	-	
Turn-Off Fall Time	tf	$R_{G}=6\Omega^{(Note 1,2)}$	-	73	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I <sub>S</sub>		-	-	-1.5	A
Diode Forward Voltage	$V_{SD}$	I <sub>S</sub> =-1.0A, V <sub>GS</sub> =0V		-0.79	-1.2	V

NOTES :

- 1. Pulse width300us, Duty cycle2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Reja is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper
- 4. The maximum current rating is package limited







 $\begin{bmatrix} 10 & V_{DS}=-15V & ID=-3.1A &$ 

**TYPICAL CHARACTERISTIC CURVES** 

#### Fig.7 Gate-Charge Characteristics

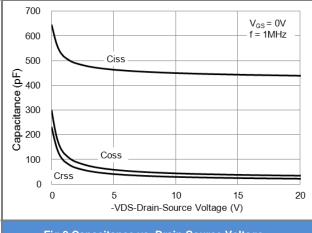
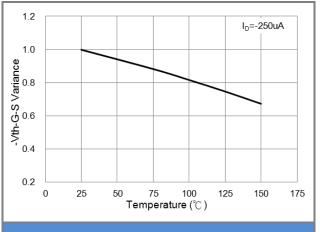


Fig.9 Capacitance vs. Drain-Source Voltage



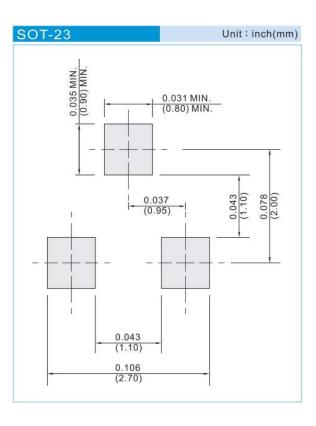
#### Fig.8 Threshold Voltage Variation with Temperature



### PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
PJA3403_R1_00001	SOT-23	3K pcs / 7" reel	A03	Halogen free
PJA3403_R2_00001	SOT-23	12K pcs / 13" reel	A03	Halogen free

### MOUNTING PAD LAYOUT





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